NSN 5961-00-551-0637

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View Online at https://aerobasegroup.com/nsn/5961-00-551-0637 **Inclosure Material:** Plastic **Overall Length:** 0.658 inches **Overall Height:** 0.150 inches **Overall Width:** 0.520 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 85.0 collector to base voltage/static/emitter open and 85.0 collector to base voltage, dc and 4.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 10.00 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 90.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0